imall

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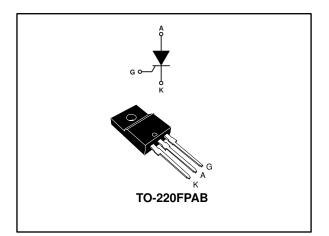
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High temperature 20 A SCRs

Datasheet - production data



Features

- High junction temperature: T_j = 150 °C
- High noise immunity dV/dt = 400 V/µs up to 150 °C
- Gate triggering current I_{GT} = 10 mA
- Peak off-state voltage V_{DRM}/V_{RRM} = 600 V
- High turn-on current rise dl/dt = 100 A/µs
- ECOPACK[®]2 compliant component
- TO-220FPAB insulated package:
 - Complies with UL standards (File ref: E81734)
 - Insulated voltage: 2000 V_{RMS}

Applications

- Motorbike voltage regulator circuits
- Inrush current limiting circuits
- Motor control circuits and starters
- Light dimmers
- Solid state relays

Description

Packaged in an insulated TO-220FPAB, this device offers high thermal performance during operation of up to 20 A_{RMS} , thanks to a junction temperature of up to 150 °C.

This insulated fullpack package allows a back to back configuration.

The combination of noise immunity and low gate triggering current allows to design strong and compact control circuits.

Table 1: Device summary

Order code	Package	V _{DRM} /V _{RRM}	Ідт
TN2010H-6FP	TO-220FPAB	600 V	10 mA

August 2017

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This is information on a product in full production.

1 **Characteristics**

Symbol	Parameter			Value	Unit
I _{T(RMS)}	RMS on-state current (180 ° conduction angle)	T _c = 80 °C	20	А	
			$T_c = 80 \ ^{\circ}C$	12.7	
I _{T(AV)}	Average on-state current (180 ° conduction angle)		$T_c = 99 \ ^\circ C$	10	А
	(100 conduction angle)		T _c = 112 °C	8	
	Non repetitive surge peak on-	Non repetitive surge peak on-state current		197	A
Ітѕм	(T _j initial = 25 °C)		$t_p = 10 \text{ ms}$	180	
l ² t	I ² t value for fusing	$t_p = 10 \text{ ms}$	162	A ² s	
dl/dt	Critical rate of rise of on-state $I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$	f = 60 Hz	100	A/µs	
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage		$t_p = 10 \text{ ms}$	700	V
Ідм	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	Α
P _{G(AV)}	Average gate power dissipation $T_j = 150 \text{ °C}$			1	W
T _{stg}	Storage junction temperature range			-40 to +150	°C
Tj	Operating junction temperature range			-40 to +150	°C
TL	Maximum lead temperature for soldering during 10 s			260	°C
VINS(RMS)	Insulation RMS voltage, 60 seconds			2000	V

Table 3: Electrical characteristics (T_j = 25 °C unless otherwise specified)

Symbol	Symbol Test conditions				
1			Тур.	5	mA
I _{GT}	V_D = 12 V, R _L = 33 Ω		Max.	10	ША
V _{GT}			Max.	1.3	V
V _{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$	Min.	0.1	V	
Ін	I⊤ = 500 mA, gate open	Max.	40	mA	
١L	$I_G = 1.2 \times I_{GT}$			60	mA
dV/dt	$V_D = 402 \text{ V}, \text{ gate open}$ $T_j = 150 ^{\circ}\text{C}$		Min.	400	V/µ s
t _{gt}	$I_{TM} = 40 \text{ A}, V_D = 402 \text{ V}, I_G = 20 \text{ mA}, (dI_G/dt) \text{ max} = 0.2 \text{ A}/\mu \text{s}$			1.9	μs
tq			Тур.	70	μs

Characteristics

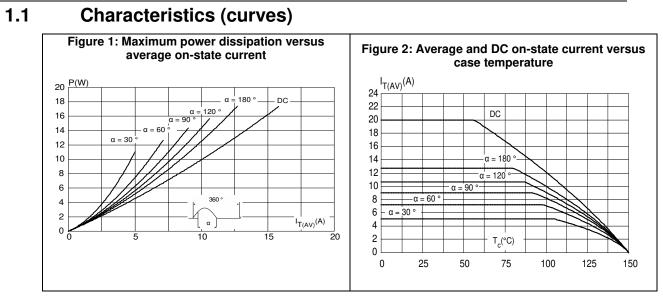
Table 4: Static characteristics						
Symbol	Test conditions			Value	Unit	
V _{TM}	$I_{TM} = 40 \text{ A}, t_p = 380 \ \mu s$	T _j = 25 °C	Max.	1.6	v	
V _{TO}	Threshold voltage	T _j = 150 °C	Max.	0.82		
RD	Dynamic resistance	T _j = 150 °C	Max.	17.5	mΩ	
		T _j = 25 °C		5	μA	
I _{drm} , I _{rrm}	$V_D = V_{DRM}, V_R = V_{RRM}$	T _j = 125 °C	Max.	2		
		T _j = 150 °C		3.9	mA	

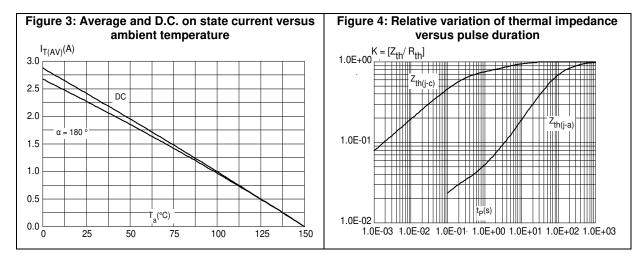
Table 5: Thermal parameters

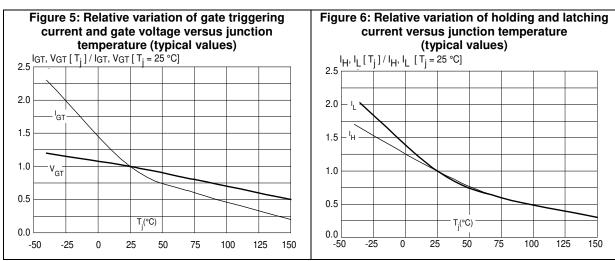
	Symbol	Parameter	Value	Unit	
ſ	R _{th(j-c)}	Junction to case (DC)	Max.	4.0	°C/W
	Rth(j-a)	Junction to ambient (DC)	Тур.	60	-C/W



Characteristics





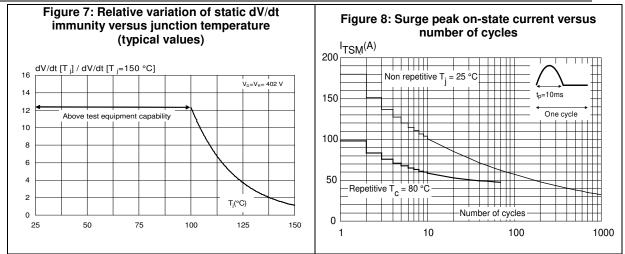


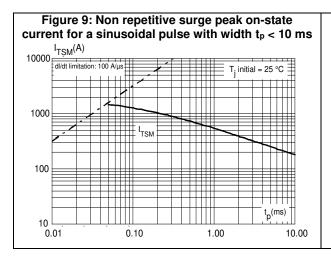
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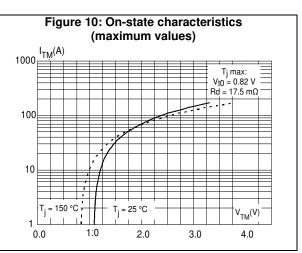


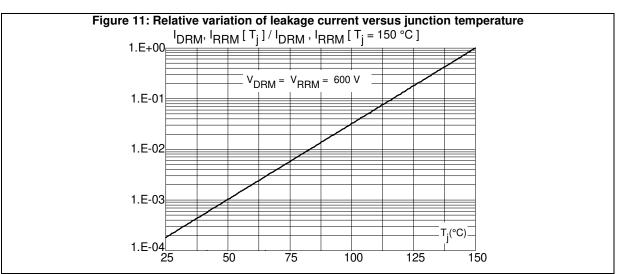
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Characteristics









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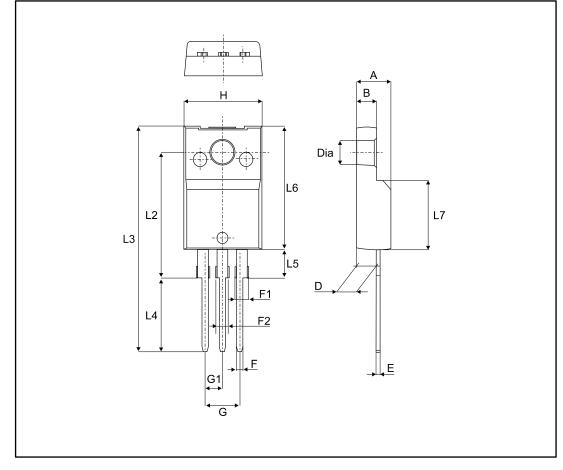
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free, halogen-free package
- Recommended torque value (TO-220FPAB): 0.4 to 0.6 N.m

2.1 TO-220AB package information







6FP	P Package information					
	Table 6: TO-220FPAB package mechanical data					
		Dimensions				
Ref.	Millir	neters	Inc	hes		
	Min.	Max.	Min.	Max.		
А	4.40	4.60	0.1739	0.1818		
В	2.5	2.7	0.0988	0.1067		
D	2.50	2.75	0.0988	0.1087		
E	0.45	0.70	0.0178	0.0277		
F	0.75	1.0	0.0296	0.0395		
F1	1.15	1.70	0.0455	0.0672		
F2	1.15	1.70	0.0455	0.0672		
G	4.95	5.20	0.1957	0.2055		
G1	2.40	2.70	0.0949	0.1067		
Н	10.00	10.40	0.3953	0.4111		
L2	16.0	00 typ.	0.632	24 typ.		
L3	28.60	30.60	1.1304	1.2095		
L4	9.80	10.6	0.3874	0.4190		
L5	2.90	3.60	0.1146	0.1423		
L6	15.90	16.40	0.6285	0.6482		
L7	9.00	9.30	0.3557	0.3676		
Dia	3.0	3.20	0.1186	0.1265		

3 Ordering information

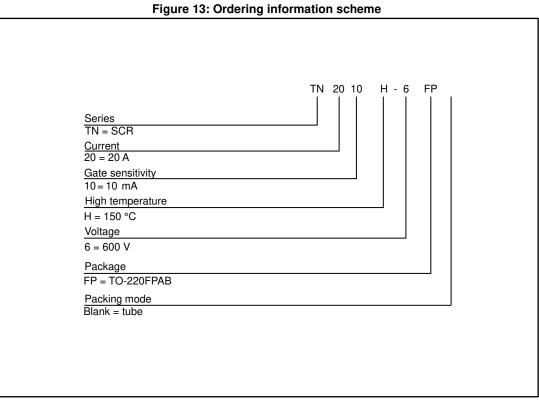


Table 7: Ordering information					
Order code Marking Package Weight Base qty. Delivery mode					
TN2010H-6FP	TN2010H6	TO-220FPAB	2.0 g	50	Tube

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
01-Aug-2017	1	Initial release.

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